L Number	Hits	Search Text	DB	Time stamp
-	29676	magnetic near2 memory	USPAT;	2004/06/27
			US-PGPUB; EPO; JPO; DERWENT;	23:21
-	13267	conductive adj line	IBM_TDB USPAT; US-PGPUB; EPO; JPO;	2004/06/27 22:57
-	121130	(conductive adj2 line) or (electrical adj2 line) or ((bit or word) adj line)	DERWENT; IBM_TDB USPAT; US-PGPUB; EPO; JPO;	2004/06/27 22:59
_	2237	(magnetic near2 memory) and ((conductive adj2 line) or (electrical adj2 line) or ((bit or word) adj line))	DERWENT; IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT;	2004/06/27 22:59
-	41703	magnetic near3 memory	IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT;	2004/06/27 23:43
_	2840	(magnetic near3 memory) and ((conductive adj2 line) or (electrical adj2 line) or ((bit or word) adj line))	IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT;	2004/06/27 23:44
_	183281	(current adj2 supply) or (voltage adj2 supply)	IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT;	2004/06/27 23:55
-	368	((magnetic near3 memory) and ((conductive adj2 line) or (electrical adj2 line) or ((bit or word) adj line))) and ((current adj2 supply))	IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT;	2004/06/27 23:46
_	164738	current with direction	IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT;	2004/06/28 00:31
_	46893	multipl\$4 near2 line	IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT;	2004/06/28 00:32
-	34	<pre>((magnetic near3 memory) and (((magnetic near3 memory) and ((conductive adj2 line) or (electrical adj2 line) or ((bit or word) adj line))) and ((current adj2 supply) or (voltage adj2 supply)))) and (multipl\$4 near2 line)</pre>	IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/28 00:32
-	368	<pre>(magnetic near3 memory) and (((magnetic near3 memory) and ((conductive adj2 line) or (electrical adj2 line) or ((bit or word) adj line))) and ((current adj2</pre>	USPAT; US-PGPUB; EPO; JPO; DERWENT;	2004/06/28
-	688	supply) or (voltage adj2 supply))) magnetic adj memory adj cell\$1	IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2004/06/28 01:07

				T
-	534	(magnetic adj memory adj cell\$1) and line	USPAT;	2004/06/28
			US-PGPUB;	01:07
			EPO; JPO;	
			DERWENT;	
			IBM TDB	
-	109	((magnetic adj memory adj cell\$1) and	USPAT;	2004/06/28
		line) and current adj source	US-PGPUB;	01:08
		-	EPO; JPO;	
			DERWENT;	
			IBM TDB	
_	2167	mram and line	USPAT;	2004/06/28
-	2107	I MI AM AND TIME	US-PGPUB;	01:08
			EPO; JPO;	01.00
			DERWENT;	1
			IBM TDB	
	1163	/muam and line) and source	· –	2004/06/28
-	1163	(mram and line) and source	USPAT;	2004/06/28
			US-PGPUB;	01:08
			EPO; JPO;	
			DERWENT;	1
		l	IBM_TDB	
-	633	((mram and line) and source) and supply	USPAT;	2004/06/28
			US-PGPUB;	01:09
			EPO; JPO;	
ł			DERWENT;	
i			IBM_TDB	1
_	753	((mram and line) and source) and suppl\$4	USPAT;	2004/06/28
			US-PGPUB;	01:09
			EPO; JPO;	
		•	DERWENT;	
			IBM TDB	
-	508	(((mram and line) and source) and	USPAT;	2004/06/28
		suppl\$4) and 365/\$.ccls.	US-PGPUB;	01:10
		••	EPO; JPO;	
			DERWENT;	]
			IBM TDB	
_	252	((((mram and line) and source) and	USPAT;	2004/06/28
		suppl\$4) and 365/\$.ccls.) and (chang\$3	US-PGPUB;	01:27
		with direct\$4)	EPO; JPO;	/
			DERWENT;	
			IBM TDB	
_	168	((((mram and line) and source) and	USPAT;	2004/06/28
]	100	suppl\$4) and 365/\$.ccls.) and (chang\$3	US-PGPUB;	01:27
		with direct\$4 with current)	EPO; JPO;	01.27
		with directly with cultent)	DERWENT;	
			IBM_TDB	